



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts,Customers Priority,Honest Operation,and Considerate Service",our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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Parameter	Ratings	Units
Blocking Voltage	350	V_P
Load Current	120	mA_{rms} / mA_{DC}
On-Resistance (max)	35	Ω

Features

- 3750V_{rms} Input/Output Isolation
- Low Drive Power Requirements (TTL/CMOS Compatible)
- Arc-Free With No Snubbing Circuits
- FCC Compatible
- VDE Compatible
- No EMI/RFI Generation
- Machine Insertable, Wave Solderable
- Surface Mount Tape & Reel Packages Available

Applications

- Telecom Switching
 - Tip/Ring Circuits
 - Modem Switching (Laptop, Notebook, Pocket Size)
 - Hook Switch
 - Dial Pulsing
 - Ground Start
 - Ringing Injection
- Instrumentation
 - Multiplexers
 - Data Acquisition
 - Electronic Switching
 - I/O Subsystems
- Meters (Watt-Hour, Water, Gas)
- Medical Equipment-Patient/Equipment Isolation
- Security
- Aerospace
- Industrial Controls

Description

LAA110 is a dual 1-Form-A Solid State Relay that has two independently controlled, optically coupled MOSFET switches. The output MOSFET switches and photovoltaic die employ optically coupled MOSFET technology to provide 3750 V_{rms} of input-to-output isolation.

The relay outputs, that use patented OptoMOS architecture, are controlled by a highly efficient GaAlAs infrared LED.

This dual pole OptoMOS relay provides a more compact design solution than discrete single-pole relays in a variety of applications, and saves board space by incorporating both switches in a single 8-Pin package.

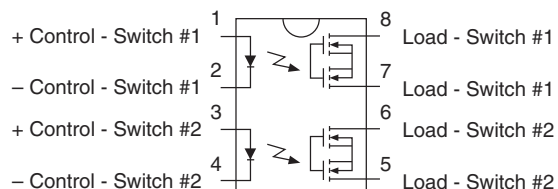
Approvals

- UL Certified Component: File E76270
- CSA Certified Component: Certificate 1175739
- EN/IEC 60950-1 Certified Component: TUV Certificate B 10 05 49410 006

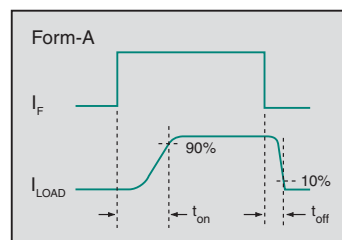
Ordering Information

Part #	Description
LAA110	8-Pin DIP (50/Tube)
LAA110S	8-Pin Surface Mount (50/Tube)
LAA110STR	8-Pin Surface Mount (1,000/Reel)
LAA110P	8-Pin Flat Pack (50/Tube)
LAA110PTR	8-Pin Flat Pack (1,000/Reel)

Pin Configuration



Switching Characteristics of Normally Open (Form A) Devices



Absolute Maximum Ratings @ 25°C

Parameter	Ratings	Units
Blocking Voltage	350	V _P
Reverse Input Voltage	5	V
Input Control Current	50	mA
Peak (10ms)	1	A
Input Power Dissipation ¹	150	mW
Total Power Dissipation ²	800	mW
Isolation Voltage, Input to Output	3750	V _{rms}
Operational Temperature	-40 to +85	°C
Storage Temperature	-40 to +125	°C

¹ Derate linearly 1.33 mW / °C

² Derate linearly 6.67 mW / °C

Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.

Electrical Characteristics @ 25°C

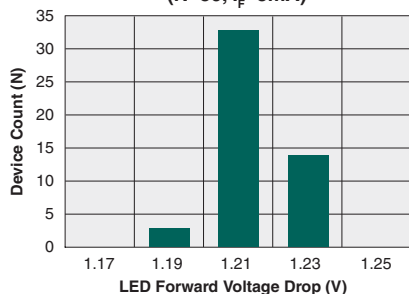
Parameter	Conditions	Symbol	Min	Typ	Max	Units
Output Characteristics						
Load Current, Continuous ¹	-	I _L	-	-	120	mA _{rms} / mA _{DC}
Peak Load Current	t=10ms	I _{LPK}	-	-	±350	mA _p
On-Resistance ²	I _L =120mA	R _{ON}	-	25	35	Ω
Off-State Leakage Current	V _L =350V _P	I _{LEAK}	-	-	1	μA
Switching Speeds	I _F =5mA, V _L =10V					
Turn-On		t _{on}	-	-	3	ms
Turn-Off		t _{off}	-	-	3	ms
Output Capacitance	V _L =50V, f=1MHz	C _{OUT}	-	25	-	pF
Input Characteristics						
Input Control Current to Activate	I _L =120mA	I _F	-	-	5	mA
Input Control Current to Deactivate	-	-	0.4	0.7	-	mA
Input Voltage Drop	I _F =5mA	V _F	0.9	1.2	1.4	V
Reverse Input Current	V _R =5V	I _R	-	-	10	μA
Common Characteristics						
Input to Output Capacitance	-	C _{I/O}	-	3	-	pF

¹ If both poles operate the load current must be derated so as not to exceed the package power dissipation value.

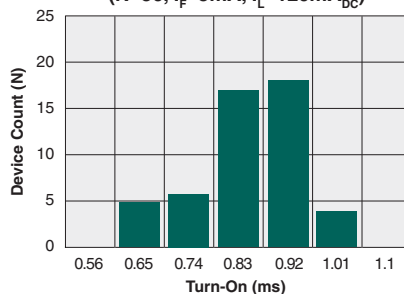
² Measurement taken within 1 second of on-time.

PERFORMANCE DATA @25°C (Unless Otherwise Noted)*

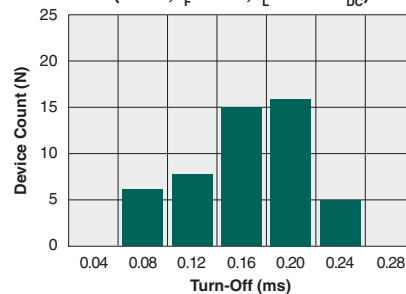
Typical LED Forward Voltage Drop
(N=50, $I_F=5\text{mA}$)



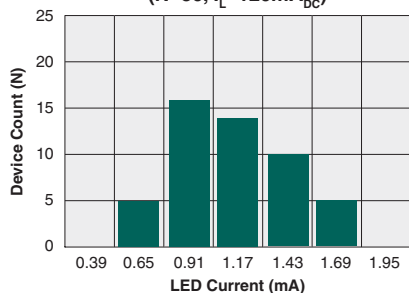
Typical Turn-On Time
(N=50, $I_F=5\text{mA}$, $I_L=120\text{mA}_{DC}$)



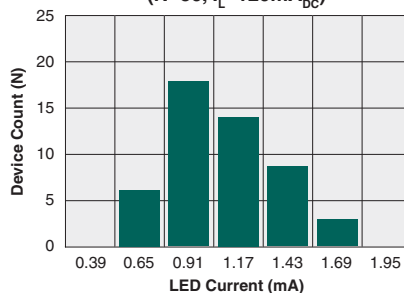
Typical Turn-Off Time
(N=50, $I_F=5\text{mA}$, $I_L=120\text{mA}_{DC}$)



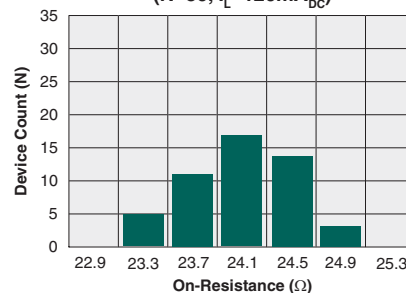
Typical I_F for Switch Operation
(N=50, $I_L=120\text{mA}_{DC}$)



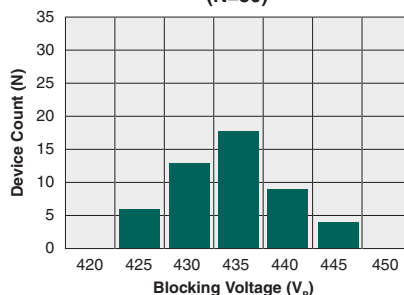
Typical I_F for Switch Dropout
(N=50, $I_L=120\text{mA}_{DC}$)



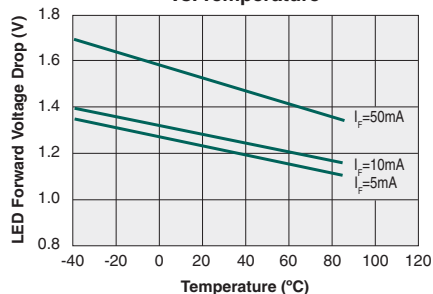
Typical On-Resistance Distribution
(N=50, $I_L=120\text{mA}_{DC}$)



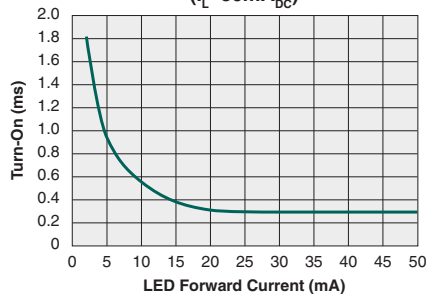
Typical Blocking Voltage Distribution
(N=50)



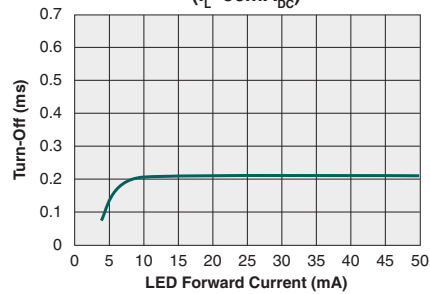
Typical LED Forward Voltage Drop
vs. Temperature



Typical Turn-On vs. LED Forward Current
($I_L=50\text{mA}_{DC}$)

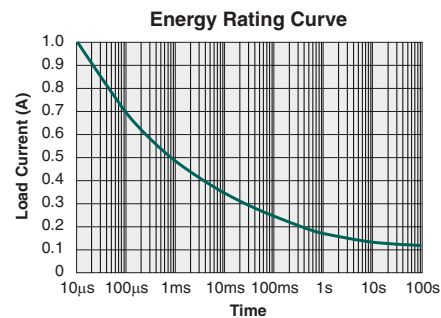
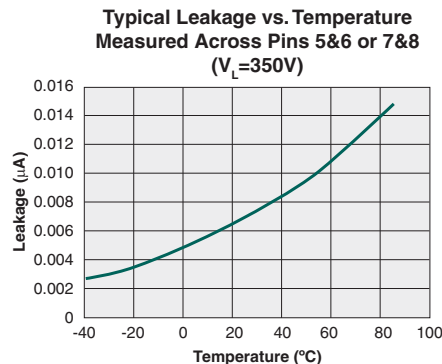
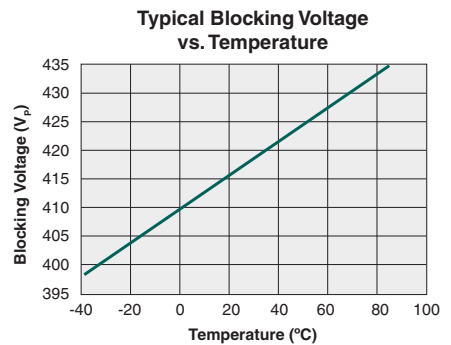
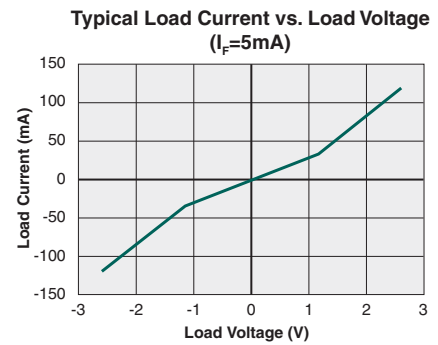
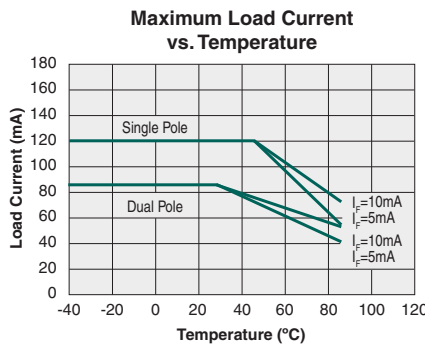
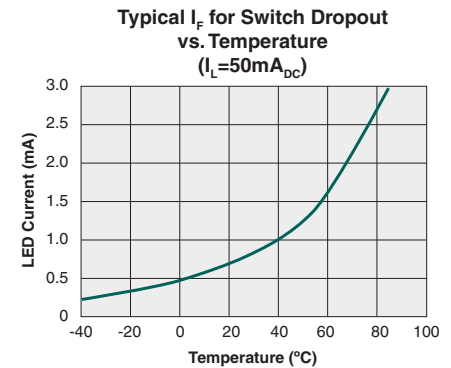
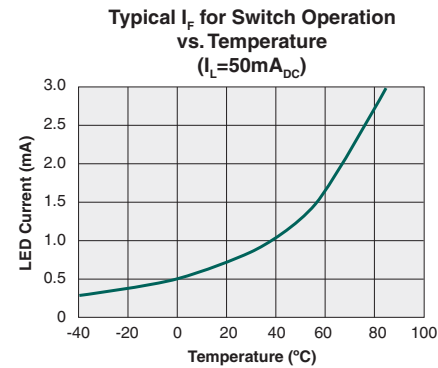
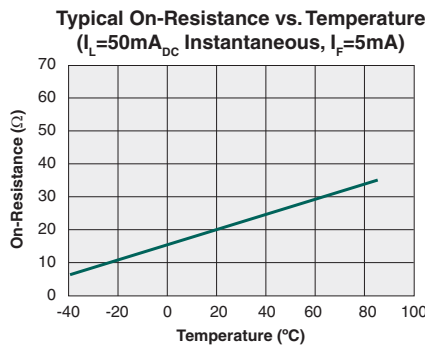
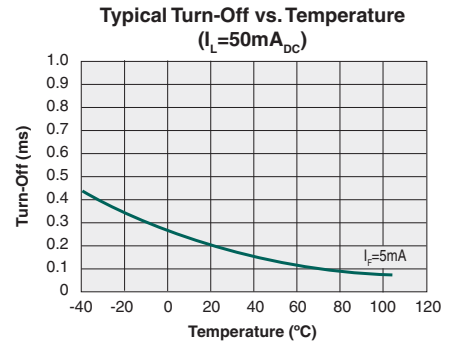
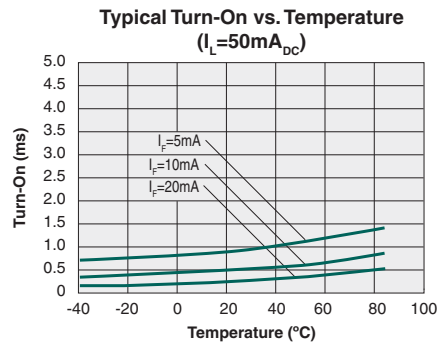
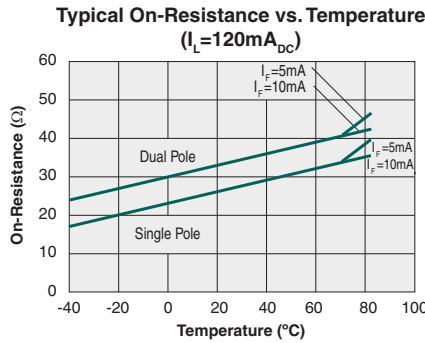


Typical Turn-Off vs. LED Forward Current
($I_L=50\text{mA}_{DC}$)



*The Performance data shown in the graphs above is typical of device performance. For guaranteed parameters not indicated in the written specifications, please contact our application department.

PERFORMANCE DATA @25°C (Unless Otherwise Noted)*



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Manufacturing Information

Moisture Sensitivity



All plastic encapsulated semiconductor packages are susceptible to moisture ingress. IXYS Integrated Circuits Division classified all of its plastic encapsulated devices for moisture sensitivity according to the latest version of the joint industry standard, **IPC/JEDEC J-STD-020**, in force at the time of product evaluation. We test all of our products to the maximum conditions set forth in the standard, and guarantee proper operation of our devices when handled according to the limitations and information in that standard as well as to any limitations set forth in the information or standards referenced below.

Failure to adhere to the warnings or limitations as established by the listed specifications could result in reduced product performance, reduction of operable life, and/or reduction of overall reliability.

This product carries a **Moisture Sensitivity Level (MSL) rating** as shown below, and should be handled according to the requirements of the latest version of the joint industry standard **IPC/JEDEC J-STD-033**.

Device	Moisture Sensitivity Level (MSL) Rating
LAA110 / LAA110S / LAA110P	MSL 1

ESD Sensitivity



This product is **ESD Sensitive**, and should be handled according to the industry standard **JESD-625**.

Reflow Profile

This product has a maximum body temperature and time rating as shown below. All other guidelines of **J-STD-020** must be observed.

Device	Maximum Temperature x Time
LAA110 / LAA110S	250°C for 30 seconds
LAA110P	260°C for 30 seconds

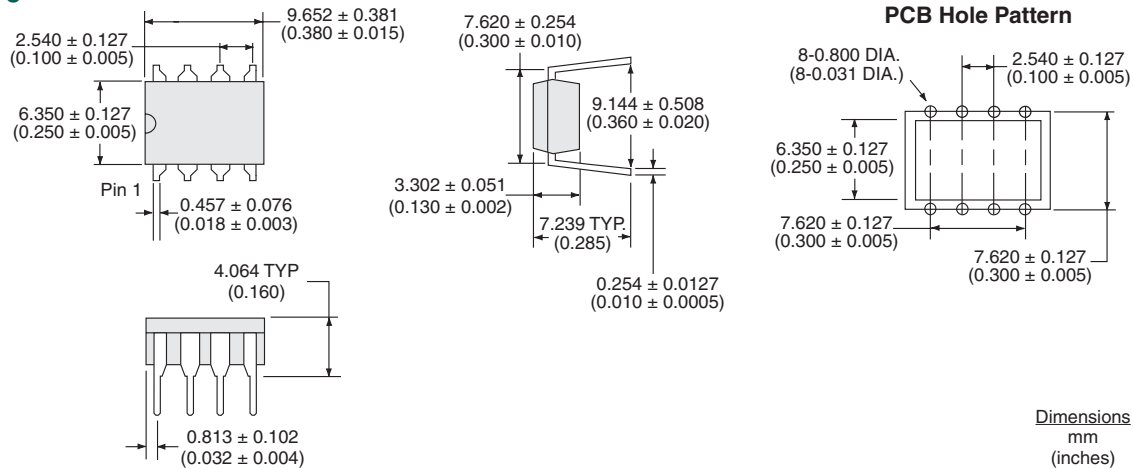
Board Wash

IXYS Integrated Circuits Division recommends the use of no-clean flux formulations. However, board washing to remove flux residue is acceptable. Since IXYS Integrated Circuits Division employs the use of silicone coating as an optical waveguide in many of its optically isolated products, the use of a short drying bake could be necessary if a wash is used after solder reflow processes. Chlorine- or Fluorine-based solvents or fluxes should not be used. Cleaning methods that employ ultrasonic energy should not be used.

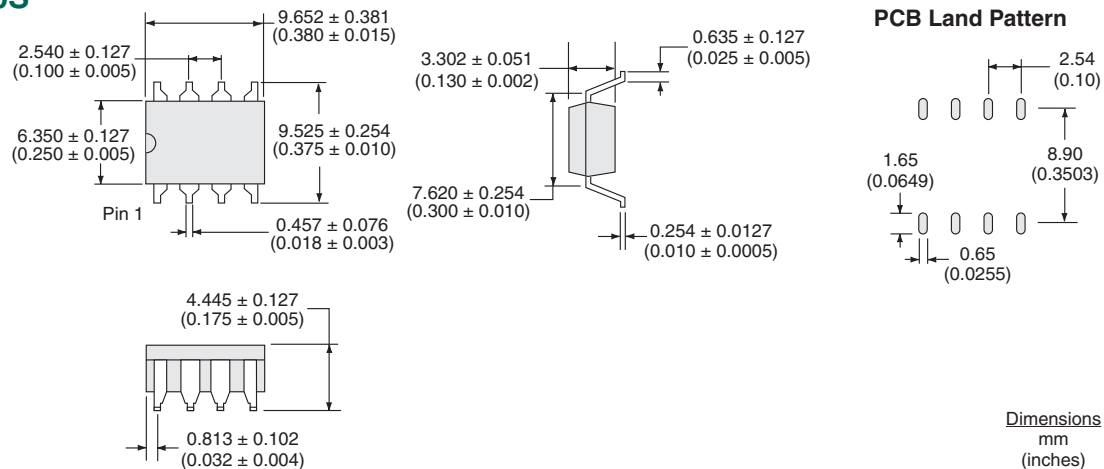


MECHANICAL DIMENSIONS

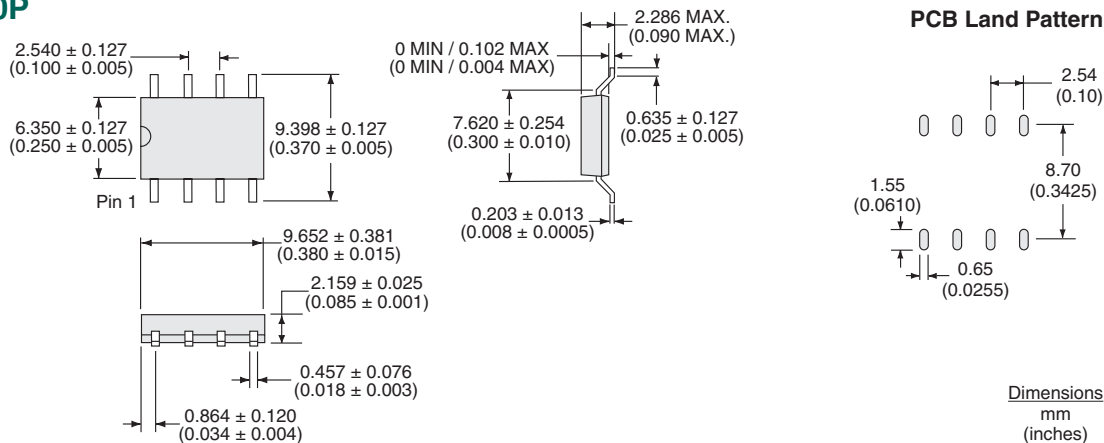
LAA110



LAA110S

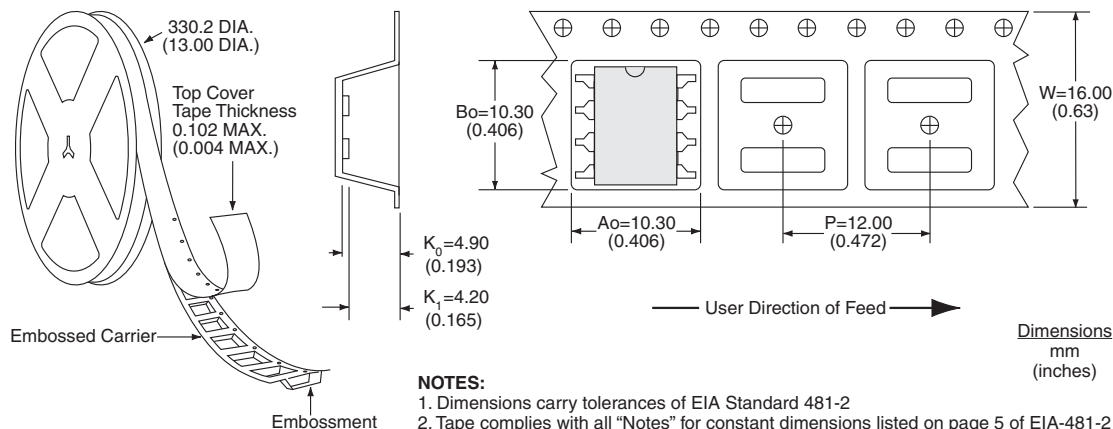


LAA110P

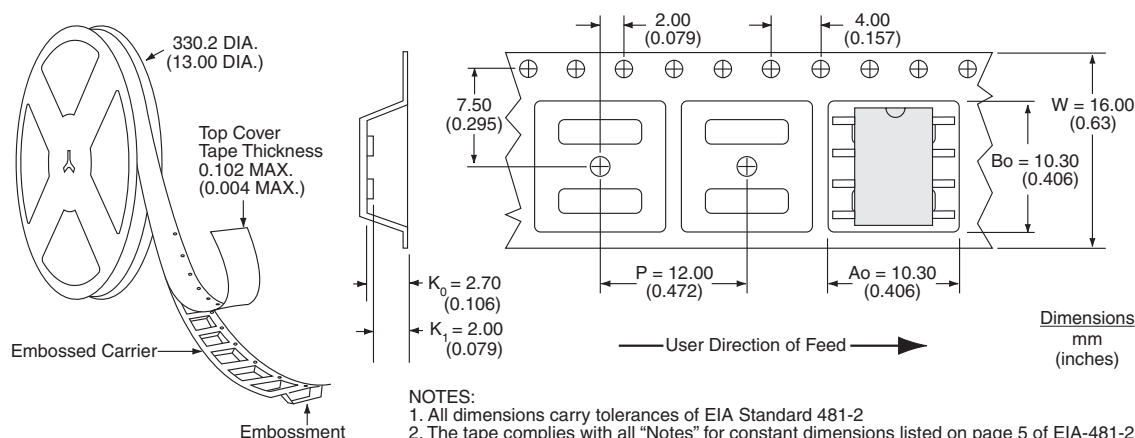


MECHANICAL DIMENSIONS

LAA110STR Tape & Reel



LAA110PTR Tape & Reel



For additional information please visit our website at: www.ixysic.com

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